



3.3V CMOS 18-BIT TO 36-BIT REGISTERED BUS EXCHANGER WITH 3-STATE OUTPUTS AND BUS-HOLD

IDT74ALVCH16282

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical $t_{SK(0)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015;
> 200V using machine model (C = 200pF, R = 0)
- V_{CC} = 1.65V to 3.6V
- CMOS power levels (0.4μW typ. static)
- Rail-to-Rail output swing for increased noise margin
- Available in TVSOP package

Drive Features for ALVCH16282:

- High Output Drivers: $\pm 24\text{mA}$
- Suitable for heavy loads

APPLICATIONS:

- SDRAM Modules
- PC Motherboards
- Workstations

DESCRIPTION:

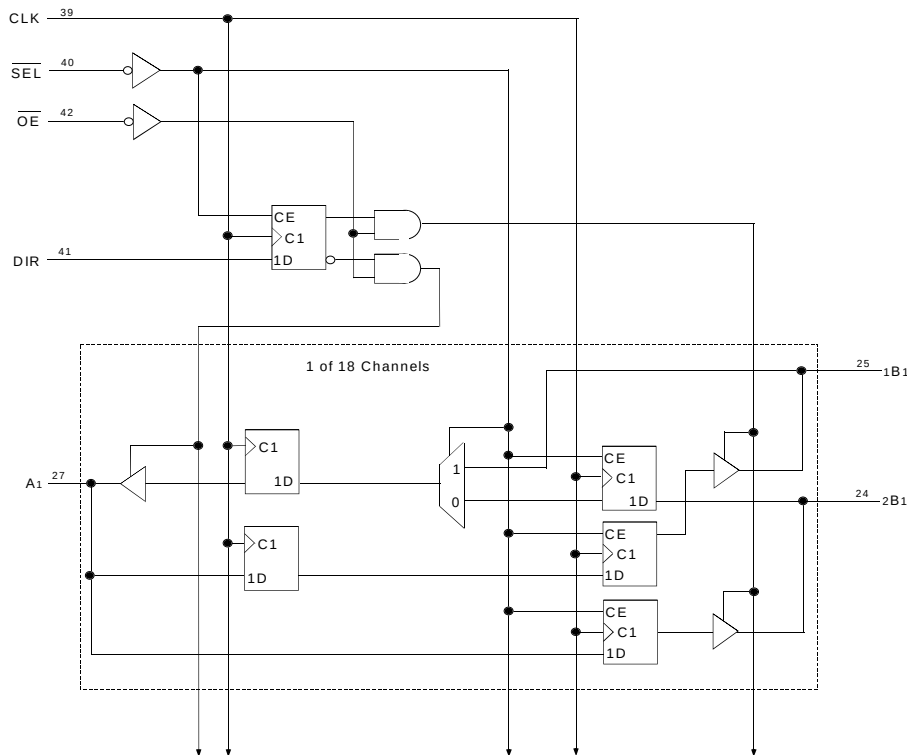
This 18-bit to 36-bit registered bus exchanger is manufactured using advanced dual metal CMOS technology. This device is intended for use in applications in which data must be transferred from a narrow high-speed bus to a wide lower-frequency bus.

The ALVCH16282 provides synchronous data exchange between the two ports. Data is stored in the internal registers on the low-to-high transition of the clock (CLK) input. For data transfer in the B-to-A direction, the select (SEL) input selects 1B or 2B data for the A outputs. For data transfer in the A-to-B direction, a two-stage pipeline is provided in the 1B path, with a single storage register in the 2B path. Data flow is controlled by the active-low output enable ($\overline{OE}$) and the DIR input. The DIR control pin is registered to synchronize the bus direction changes with the clock.

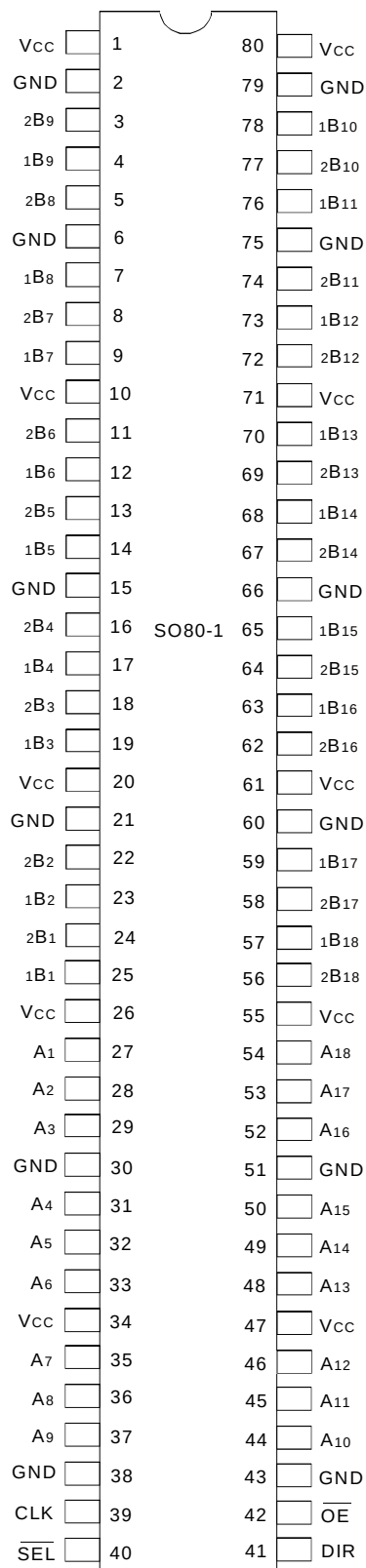
The ALVCH16282 has been designed with a $\pm 24\text{mA}$ output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

The ALVCH16282 has “bus-hold” which retains the inputs’ last state whenever the input bus goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



TVSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Description	Max.	Unit
V _{TERM} (2)	Terminal Voltage with Respect to GND	– 0.5 to + 4.6	V
V _{TERM} (3)	Terminal Voltage with Respect to GND	– 0.5 to V _{CC} + 0.5	V
T _{STG}	Storage Temperature	– 65 to + 150	°C
I _{OUT}	DC Output Current	– 50 to + 50	mA
I _{IK}	Continuous Clamp Current, V _I < 0 or V _I > V _{CC}	± 50	mA
I _{OK}	Continuous Clamp Current, V _O < 0	– 50	mA
I _{CC} I _{SS}	Continuous Current through each V _{CC} or GND	±100	mA

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NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{CC} terminals.
- All terminals except V_{CC}.

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter(1)	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	5	—	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	7	—	pF
C _{I/O}	I/O Port Capacitance	V _{IN} = 0V	7	—	pF

NOTE:

- As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description
$\overline{OE}$	3-State Output Enable Input (Active LOW)
CLK	Register Input Clock
$\overline{SEL}$	Select Input
A _x	Data Inputs or 3-State Outputs (1)
xB _x	Data Inputs or 3-State Outputs (1)
DIR	Direction Control Input

NOTE:

- These pins have "Bus-Hold." All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLES (1)

A-TO-B STORAGE ($\overline{OE} = L$ AND $DIR = H$)

Inputs			Outputs	
$\overline{SEL}$	CLK	Ax	1Bx	2Bx
H	X	X	1B ₀ ⁽²⁾	2B ₀ ⁽²⁾
L	↑	L	L ⁽³⁾	L
L	↑	H	H ⁽³⁾	H

OUTPUT ENABLE

Inputs				Outputs	
CLK	$\overline{OE}$	$\overline{SEL}$	DIR	Ax	1Bx, 2Bx
↑	H	X	X	Z	Z
↑	L	L	H	Z	Active
↑	L	L	L	Active	Z
X	L	H	X	Ao ⁽²⁾	1Bo ⁽²⁾ , 2Bo ⁽²⁾

B-TO-A STORAGE ($\overline{OE} = L$ AND $DIR = L$)

Inputs				Output
$\overline{SEL}$	CLK	1Bx	2Bx	Ax
H	↑	X	L	L ⁽⁴⁾
H	↑	X	H	H ⁽⁴⁾
L	↑	L	X	L
L	↑	H	X	H

NOTES:

1. H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High-Impedance
↑ = LOW-to-HIGH Transition
2. Output level before the indicated steady-state input conditions were established.
3. Two CLK edges are needed to propagate data.
4. Two CLK edges are needed to propagate the data. The data is loaded in the first register when $\overline{SEL}$ is LOW and propagates to the second register when $\overline{SEL}$ is HIGH.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = - 40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	VCC = 1.65V to 1.95V		0.65 x VCC	—	—	V
		VCC = 2.3V to 2.7V		1.7	—	—	
		VCC = 2.7V to 3.6V		2	—	—	
VIL	Input LOW Voltage Level	VCC = 1.65V to 1.95V		—	—	0.35 x VCC	V
		VCC = 2.3V to 2.7V		—	—	0.7	
		VCC = 2.7V to 3.6V		—	—	0.8	
IiH	Input HIGH Current	VCC = 3.6V	Vi = VCC	—	—	± 5	μA
IiL	Input LOW Current	VCC = 3.6V	Vi = GND	—	—	± 5	μA
IoZH IoZL	High Impedance Output Current (excluding bus-hold pins)	VCC = 3.6V	Vo = VCC	—	—	± 10	μA
			Vo = GND	—	—	± 10	μA
VH	Input Hysteresis	VCC = 3.3V		—	100	—	mV
ICCL ICCH ICCZ	Quiescent Power Supply Current	VCC = 3.6V VIN = GND or VCC		—	0.1	40	μA
ΔICC	Quiescent Power Supply Current Variation	One input at VCC - 0.6V, other inputs at VCC or GND		—	—	750	μA

NOTE:

1. Typical values are at VCC = 3.3V, +25°C ambient.

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditions		Min.	Typ. ⁽²⁾	Max.	Unit
IBHH IBHL	Bus-Hold Input Sustain Current	V _{CC} = 3.0V	V _I = 2.0V	– 75	—	—	μA
			V _I = 0.8V	75	—	—	
IBHH IBHL	Bus-Hold Input Sustain Current	V _{CC} = 2.3V	V _I = 1.7V	– 45	—	—	μA
			V _I = 0.7V	45	—	—	
IBHHO IBHLO	Bus-Hold Input Overdrive Current	V _{CC} = 3.6V	V _I = 0 to 3.6V	—	—	± 500	μA

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NOTES:

1. Pins with Bus-hold are identified in the pin description.
2. Typical values are at V_{CC} = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOH	Output HIGH Voltage	V _{CC} = 1.65V to 3.6V	I _{OH} = – 4mA	V _{CC} – 1.2	—	V
		V _{CC} = 1.65V	I _{OH} = – 4mA	1.2	—	
		V _{CC} = 2.3V	I _{OH} = – 6mA	2	—	
		V _{CC} = 2.3V	I _{OH} = – 12mA	1.7	—	
		V _{CC} = 2.7V		2.2	—	
		V _{CC} = 3.0V		2.4	—	
		V _{CC} = 3.0V	I _{OH} = – 24mA	2	—	
VOL	Output LOW Voltage	V _{CC} = 1.65V to 3.6V	I _{OL} = 4mA	—	0.45	V
		V _{CC} = 1.65V	I _{OL} = 4mA	—	0.45	
		V _{CC} = 2.3V	I _{OL} = 6mA	—	0.4	
			I _{OL} = 12mA	—	0.7	
		V _{CC} = 2.7V	I _{OL} = 12mA	—	0.4	
		V _{CC} = 3.0V	I _{OL} = 24mA	—	0.55	

NOTE:

1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range. T_A = – 40°C to + 85°C.

OPERATING CHARACTERISTICS, $T_A = 25^\circ\text{C}$

Symbol	Parameter	Test Conditions	$V_{CC} = 2.5V \pm 0.2V$	$V_{CC} = 3.3V \pm 0.3V$	Unit
			Typical	Typical	
CPD	Power Dissipation Capacitance Outputs enabled	$C_L = 0\text{pF}$, $f = 10\text{MHz}$	282	310	pF
CPD	Power Dissipation Capacitance Outputs disabled		208	228	pF

SWITCHING CHARACTERISTICS ⁽¹⁾

Symbol	Parameter	$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 2.7V$		$V_{CC} = 3.3V \pm 0.3V$		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
f_{MAX}		150	—	150	—	150	—	MHz
t_{PLH} t_{PHL}	Propagation Delay CLK to Ax	1	6.1	—	5.5	1.4	5	ns
t_{PLH} t_{PHL}	Propagation Delay CLK to xBx	1.2	6.3	—	5.7	1.6	5.3	ns
t_{PZH} t_{PZL}	Output Enable Time CLK to Ax	1.5	6.5	1.3	6.1	1.2	5.7	ns
t_{PZH} t_{PZL}	Output Enable Time CLK to xBx	1.5	6.5	1.3	6.1	1.2	5.7	ns
t_{PHZ} t_{PLZ}	Output Disable Time CLK to Ax	1.5	6.9	1.3	6.3	1.2	5.7	ns
t_{PHZ} t_{PLZ}	Output Disable Time CLK to xBx	1.5	6.9	1.3	6.3	1.2	5.7	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to Ax	1.3	6.9	—	6.3	1.2	5.7	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to xBx	2.3	8.7	—	8.1	2.3	7.4	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OE}$ to Ax	1.5	7	—	5.6	1.8	5.7	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OE}$ to xBx	2.1	7.9	—	6.4	2.3	6.4	ns
t_{SU}	Setup Time, Ax data before CLK $\uparrow$	2.4	—	2.3	—	2	—	ns
t_{SU}	Setup Time, xBx data before CLK $\uparrow$	2.2	—	2.2	—	1.8	—	ns
t_{SU}	Setup Time, DIR before CLK $\uparrow$	2.2	—	2.1	—	1.7	—	ns
t_{SU}	Setup Time, $\overline{SEL}$ before CLK $\uparrow$	2	—	2	—	1.8	—	ns
t_H	Hold Time, Ax data after CLK $\uparrow$	0.5	—	0.5	—	0.7	—	ns
t_H	Hold Time, xBx data after CLK $\uparrow$	0.5	—	0.5	—	0.6	—	ns
t_H	Hold Time, DIR after CLK $\uparrow$	0.5	—	0.5	—	0.5	—	ns
t_H	Hold Time, $\overline{SEL}$ after CLK $\uparrow$	0.7	—	0.7	—	0.8	—	ns
t_W	Pulse Width, CLK HIGH or LOW	3.3	—	3.3	—	3.3	—	ns

NOTE:

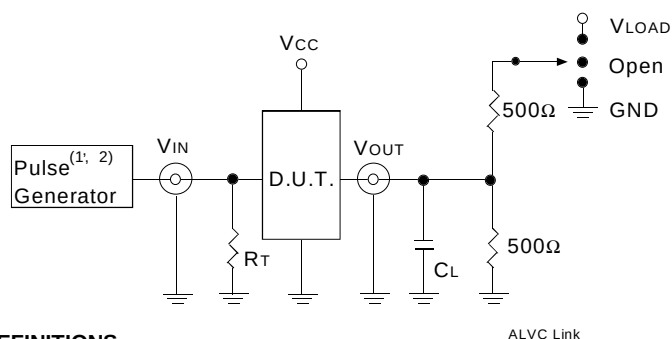
1. See test circuits and waveforms. $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$.

TEST CIRCUITS AND WAVEFORMS:

TEST CONDITIONS

Symbol	V _{CC} (1)= 3.3V ± 0.3V	V _{CC} (1)= 2.7V	V _{CC} (2)= 2.5V ± 0.2V	Unit
V _{LOAD}	6	6	2 x V _{CC}	V
V _{IH}	2.7	2.7	V _{CC}	V
V _T	1.5	1.5	V _{CC} /2	V
V _{LZ}	300	300	150	mV
V _{HZ}	300	300	150	mV
C _L	50	50	30	pF

TEST CIRCUITS FOR ALL OUTPUTS



DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

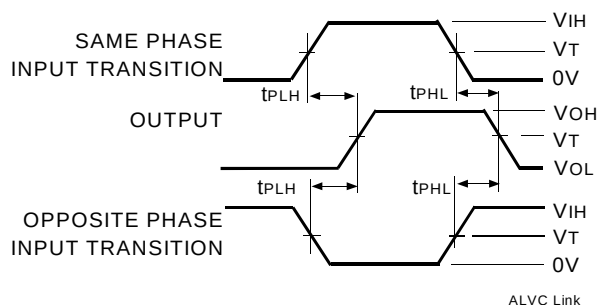
NOTES:

1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2ns.

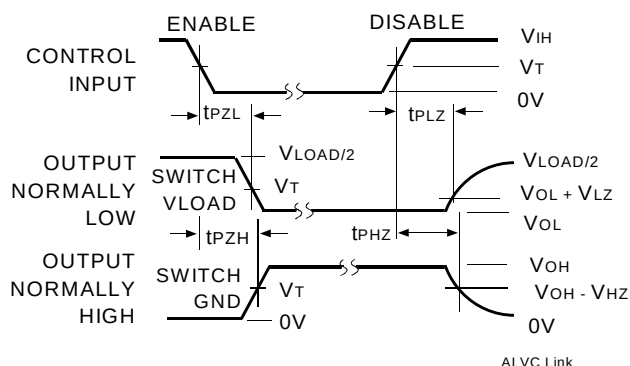
SWITCH POSITION

Test	Switch
Disable Low Enable Low	V _{LOAD}
Disable High Enable High	GND
All Other tests	Open

PROPAGATION DELAY



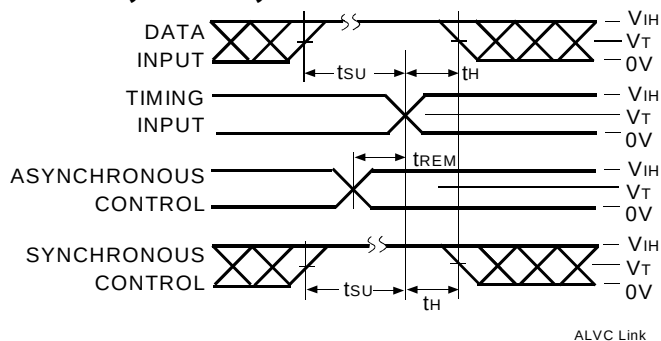
ENABLE AND DISABLE TIMES



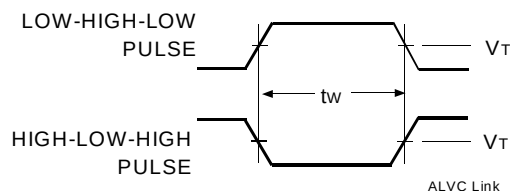
NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

SET-UP, HOLD, AND RELEASE TIMES



PULSE WIDTH



ORDERING INFORMATION

IDT	XX	ALVC	X	XXX	XXX	XX	
Temp. Range		Bus-Hold		Family	Device Type	Package	
						DF	Thin Very Small Outline Package (SO80-1)
						282	18-Bit To 36-Bit Registered Bus Exchanger with 3-State Outputs
						16	Double-Density with Resistors, $\pm 24\text{mA}$
						H	Bus-Hold
						74	-40°C to +85°C



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